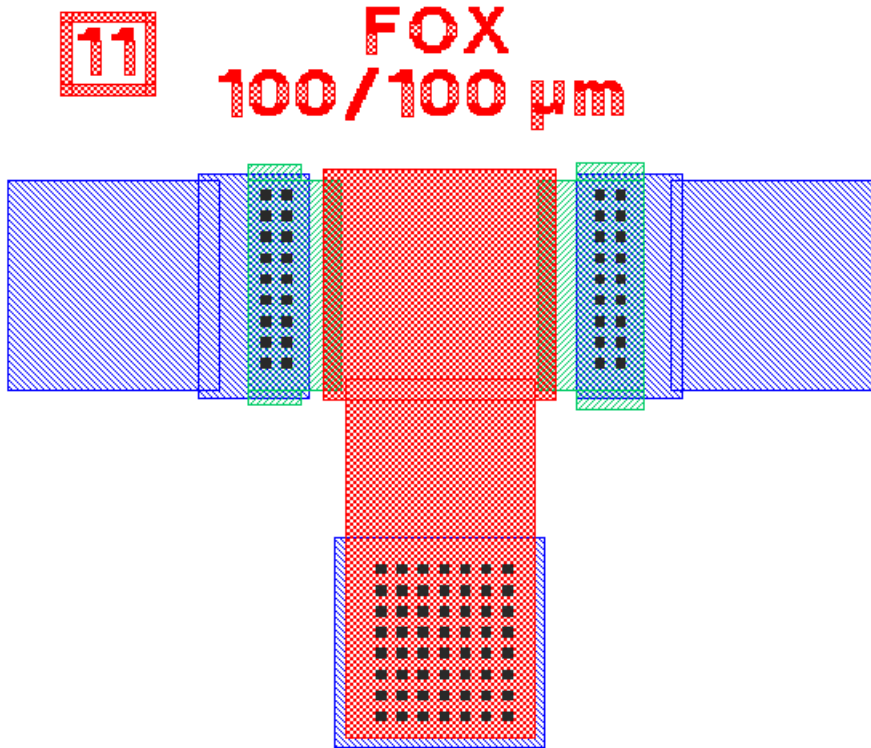


Field Oxide MOSFET

Important Details

- Gate poly-Si sits on field oxide
- W/L = 100/100 μm



Masks:  ACTV  POLY  CONT  METL